NPN Epitaxial Silicon Transistor

KSC2328A

Features

- Audio Power Amplifier Application
- Complement to KSA928A
- 3 W Output Application

ABSOLUTE MAXIMUM RATINGS

(Values are at T_A = 25°C unless otherwise noted.)

Symbol	Parameter	Value	Unit
V _{CBO}	Collector-Base Voltage	30	V
V _{CEO}	Collector-Emitter Voltage	30	V
V _{EBO}	Emitter-Base Voltage	5	V
۱ _C	Collector Current	2	А
TJ	Junction Temperature	150	°C
T _{STG}	Storage Temperature	–55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

(Values are at $T_A = 25^{\circ}C$ unless otherwise noted.) (Note 1)

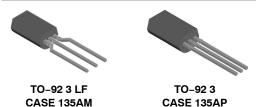
Symbol	Parameter	Value	Unit
PD	Power Dissipation	1000	mW
	Derate Above 25°C	8.0	mW/°C
$R_{ hetaJA}$	Thermal Resistance, Junction-to-Ambient	125	°C/W

PCB size: FR-4, 76 mm \times 114 mm \times 1.57 mm (3.0 inch \times 4.5 inch \times 0.062 inch) 1. with minimum land pattern size.



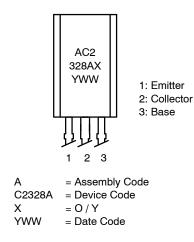
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CASE 135AP

MARKING DIAGRAM



ORDERING INFORMATION

Device	Package	Shipping
KSC2328AOTA	TO–92 3 LF (Pb–Free)	2000 / Fan-Fold
KSC2328AYBU	TO–92 3 (Pb–Free)	6000 / Bulk Bag
KSC2328AYTA	TO–92 3 LF (Pb–Free)	2000 / Fan-Fold

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ELECTRICAL CHARACTERISTICS

(Values are at $T_A = 25^{\circ}C$ unless otherwise noted.)

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
BV _{CBO}	Collector-Base Breakdown Voltage	I _C = 100 μA, I _E = 0	30	-	-	V
BV _{CEO}	Collector-Emitter Breakdown Voltage	I _C = 10 mA, I _B = 0	30	-	-	V
BV_{EBO}	Emitter-Base Breakdown Voltage	I _E = 1 mA, I _C = 0	5	-	-	V
I _{CBO}	Collector Cut-Off Current	$V_{CB} = 30 \text{ V}, \text{ I}_{E} = 0$	-	-	100	nA
I _{EBO}	Emitter Cut-Off Current	$V_{EB} = 5 V, I_{C} = 0$	-	-	100	nA
h _{FE}	DC Current Gain	$V_{CE} = 2 V, I_{C} = 500 mA$	100	-	320	
V _{BE} (on)	Base-Emitter On Voltage	$V_{CE} = 2 V, I_{C} = 500 mA$	-	-	1.0	V
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C = 1.5 A, I _B = 0.03 A	-	-	2.0	V
f _T	Current Gain Bandwidth Product	$V_{CE} = 2 V, I_C = 500 mA$	-	120	-	MHz
C _{ob}	Collector Output Capacitance	V _{CB} = 10 V, I _E = 0, f = 1 MHz	-	30	-	pF

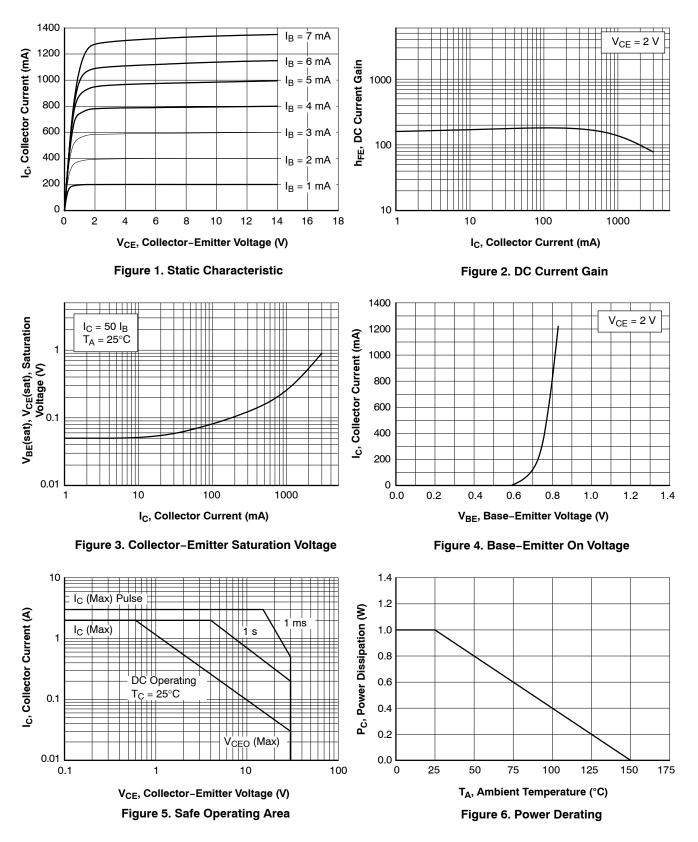
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

h_{FE} CLASSIFICATION

Classification	0	Y
h _{FE}	100 ~ 200	160 ~ 320

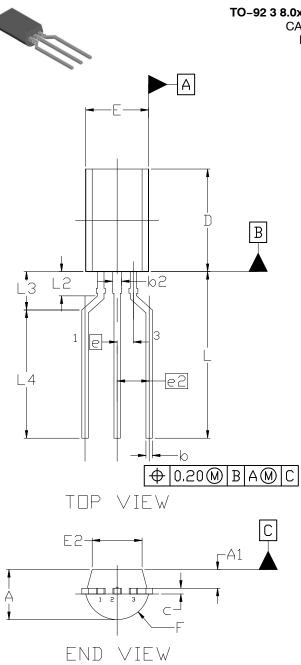
KSC2328A

TYPICAL PERFORMANCE CHARACTERISTICS



MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS





TO-92 3 8.0x4.9 (LEADFORMED) CASE 135AM

ISSUE B

DATE 14 JAN 2021

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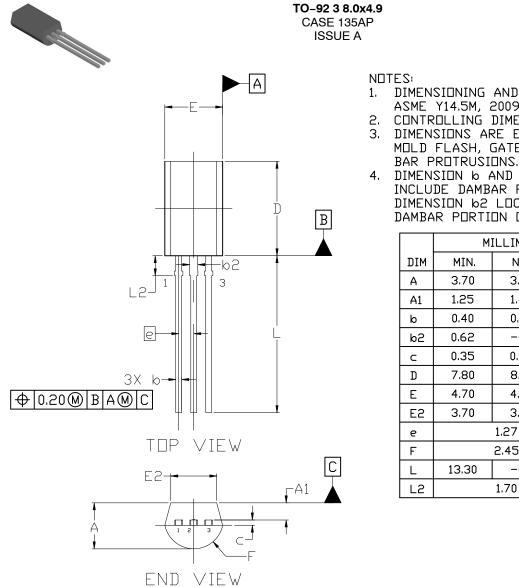
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- 3. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, GATE REMAINS AND TIE BAR PROTRUSIONS.
- 4. DIMENSION & AND &2 DOES NOT INCLUDE DAMBAR PROTRUSION. DIMENSION &2 LOCATED ABOVE THE DAMBAR PORTION OF MIDDLE LEAD.

	MILLIMETERS		
DIM	MIN.	NDM.	MAX.
А	3.70	3.90	4.10
A1	1.25	1.45	1.65
b	0.35	0.50	0.60
b2	0.62		0.78
С	0.35	0.45	0.55
D	7.80	8.00	8.20
Е	4.70	4.90	5.10
E2	3.70	3.90	4.10
е	1.27 BSC		
e2	2.50 BSC		
F	2.45 REF		
L	13.00 REF		
L2	1.50		1.90
L3	2.60		3.40
L4	10.40 REF		

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	MILLIMETERS			
DIM	MIN.	NDM.	MAX.	
А	3.70	3.90	4.10	
A1	1.25	1.45	1.65	
b	0.40	0.50	0.60	
b2	0.62		0.78	
с	0.35	0.45	0.55	
D	7.80	8.00	8.20	
E	4.70	4.90	5.10	
E2	3.70	3.90	4.10	
e	1.27 BSC			
F	2.45 REF			
L	13.30		14.20	
L2	1.70 REF			

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